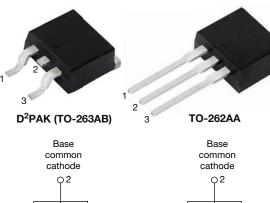
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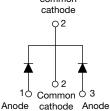
Vishay Semiconductors

High Performance Schottky Rectifier, 2 x 20 A





SHAY



Anode cathode Anode

VS-42CTQ030-1-M3

PRIMARY CHARACTERISTICS								
I _{F(AV)}	2 x 20 A							
V _R	30 V							
V _F at I _F	0.38 V							
I _{RM}	183 mA at 125 °C							
T _J max.	150 °C							
E _{AS}	13 mJ							
Package	D ² PAK (TO-263AB), TO-262AA							
Circuit configuration	Common cathode							

FEATURES

- 150 °C T_J operation
- · Center tap configuration
- Very low forward voltage drop
- High frequency operation



HALOGEN

FREE

- Guard ring for enhanced ruggedness and long term reliability
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 $^{\circ}\mathrm{C}$
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

This center tap Schottky rectifier module has been optimized for very low forward voltage drop, with moderate leakage. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	CHARACTERISTICS	VALUES	UNITS						
I _{F(AV)}	Rectangular waveform	40	А						
V _{RRM}		30	V						
I _{FSM}	t _p = 5 μs sine	1100	A						
V _F	20 A_{pk} , T_J = 125 °C (per leg)	0.38	V						
TJ	Range	-55 to +150	°C						

VOLTAGE RATINGS									
PARAMETER	SYMBOL	VS-42CTQ030S-M3 VS-42CTQ030-1-M3	UNITS						
Maximum DC reverse voltage	V _R	30	V						
Maximum working peak reverse voltage	V _{RWM}	55	v						

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VS-42CTQ030S-M3, VS-42CTQ030-1-M3

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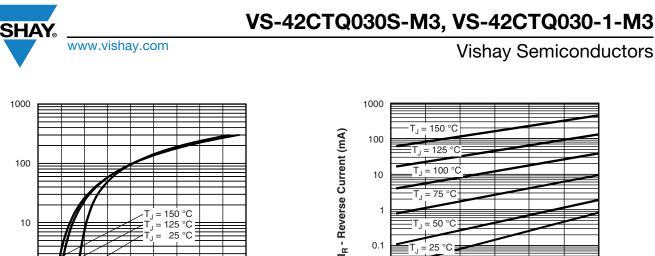
ABSOLUTE MAXIMUM RATINGS								
PARAMETER		SYMBOL	TEST COND	VALUES	UNITS			
Maximum average	per leg			20				
forward current See fig. 5	per device	I _{F(AV)}	50 % duty cycle at T_{C} = 121 °C	40				
Maximum peak one cycle r	on-repetitive		5 µs sine or 3 µs rect. pulse Following any rated loa		1100	A		
surge current per leg See fig. 7		I _{FSM}	10 ms sine or 6 ms rect. pulse Condition and with rated V _{RRM} applied		360			
Non-repetitive avalanche energy per leg E _{AS}		E _{AS}	T _J = 25 °C, I _{AS} = 3 A, L = 2.90 mH		13	mJ		
Repetitive avalanche currer	nt per leg	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		3	А		

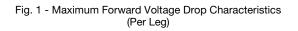
ELECTRICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CC	NDITIONS	VALUES	UNITS				
		20 A	T _{.1} = 25 °C	0.48	V				
Maximum forward voltage drop per leg	V _{FM} ⁽¹⁾	40 A	$-1_{j}=25$ C	0.57					
See fig. 1	VFM ()	20 A	– T.I = 125 °C	0.38					
		40 A	1j = 125 C	0.51					
Maximum reverse leakage current per leg	I _{RM} ⁽¹⁾	T _J = 25 °C	V - Reted V	3	mA				
See fig. 2	IRM ("	T _J = 125 °C	- V _R = Rated V _R	183					
Threshold Voltage	V _{F(TO)}			0.22	V				
Forward slope resistance	r _t	$T_J = T_J maximum$		6.76	mΩ				
Maximum junction capacitance per leg	CT	V _R = 5 V _{DC} (test signal rang	2840	pF					
Typical series inductance per leg	L _S	Measured lead to lead 5 m	8.0	nH					
Maximum voltage rate of change	dV/dt	Rated V _R	10 000	V/µs					

Note

⁽¹⁾ Pulse width < 300 μ s, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction and storage temperature range		T _J , T _{Stg}		-55 to 150	°C			
Maximum thermal resistance, junction to case per leg		P	DC operation	2.0	°C/W			
Maximum thermal resistance, junction to case per package		R _{thJC}		1.0				
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.50				
Approvimento woight				2	g			
Approximate weight				0.07	oz.			
minimum				6 (5)	kgf ⋅ cm			
Mounting torque	maximum			12 (10)	(lbf ⋅ in)			
Marking davias			Case style D ² PAK (TO-263AB)	42CT0	2030S			
Marking device			Case style TO-262AA	42CTC	2030-1			





V_{FM} - Forward Voltage Drop (V)

1.0

0.8

0.4 0.6 = 150 °C

= 125 °C

25 °C = =

1.2 1.4 1.6

1.8

I_F - Instantaneous Forward Current (A)

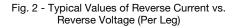
100

10

0

0.2

100 = 125 °C = 100 °C 10 = 75 °C 1 = 50 °C 0.1 25 °C 0.01 5 10 15 20 25 30 0 V_R - Reverse Voltage (V)



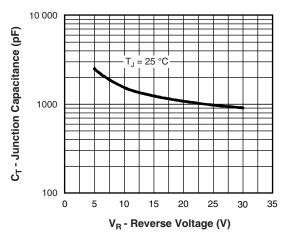
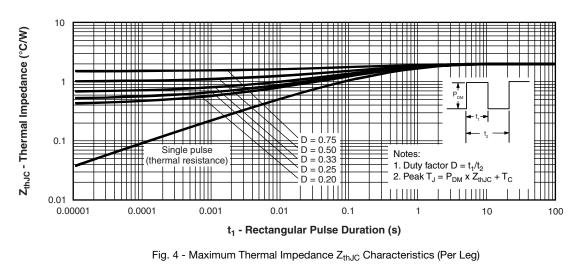


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

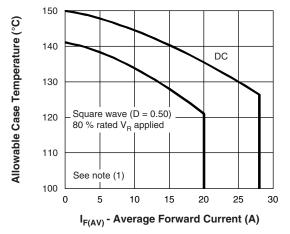


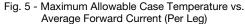
Revision: 21-Dec-2021 Document Number: 94940 3 For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000



VS-42CTQ030S-M3, VS-42CTQ030-1-M3

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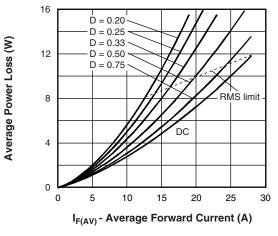


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

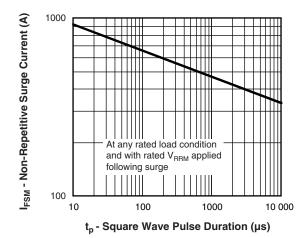


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

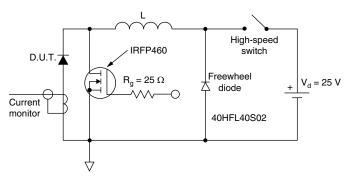


Fig. 8 - Unclamped Inductive Test Circuit

Note

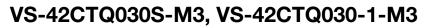
- ⁽¹⁾ Formula used: $T_C = T_J (Pd + Pd_{REV}) \times R_{thJC}$;
- $\begin{array}{l} \mbox{Pd} = \mbox{forward power loss} = \mbox{I}_{F(AV)} \times \mbox{V}_{FM} \mbox{ at } (\mbox{I}_{F(AV)}/D) \mbox{ (see fig. 6);} \\ \mbox{Pd}_{REV} = \mbox{inverse power loss} = \mbox{V}_{R1} \times \mbox{I}_{R} \mbox{ (1 D); } \mbox{I}_{R} \mbox{ at } \mbox{V}_{R1} = \mbox{ 10 V} \end{array}$

Revision: 21-Dec-2021

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Document Number: 94940

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ORDERING INFORMATION TABLE

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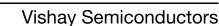
VISHAY

Device code	vs-	42	С	т	Q	030	S	TRL	-M3
		(2)	(3)	(4)	(5)	6		(8)	(9)
		\bigcirc	\bigcirc	\bigcirc	Ŭ	\bigcirc	Ċ	C	C
	<u>비</u> ·		-	niconduo	-	oduct			
	2 -								
	3 -	 Circuit configuration: C = common cathode T = TO 220 							
	4 -	T = TO-220							
	5 -	Sch	ottky "G	" series					
	6 -	· Volt	tage rati	ng (030	= 30 V))			
	7 -	• s	= D ² PA	K (TO-2	263AB)				
		• -1	= TO-2	62AA					
	8 -	• N	one = tu	ibe					
		• TI	RL = tap	be and r	eel (left	oriented	d - for D	² PAK (ГО-263
		• TI	RR = ta	pe and r	eel (righ	nt orient	ed - for	D ² PAK	(TO-26
	9 -			gen-free					

ORDERING INFORMATION									
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION							
VS-42CTQ030S-M3	50	Antistatic plastic tubes							
VS-42CTQ030STRL-M3	800	13" diameter plastic tape and reel							
VS-42CTQ030STRR-M3	800	13" diameter plastic tape and reel							
VS-42CTQ030-1-M3	50	Antistatic plastic tubes							

LINKS TO RELATED DOCUMENTS								
Dimensions	D ² PAK (TO-263AB)	www.vishay.com/doc?96164						
	TO-262AA	www.vishay.com/doc?96165						
Part marking information	D ² PAK (TO-263AB)	www.vishay.com/doc?95444						
	TO-262AA	www.vishay.com/doc?95443						
Packaging information		www.vishay.com/doc?96424						

Outline Dimensions

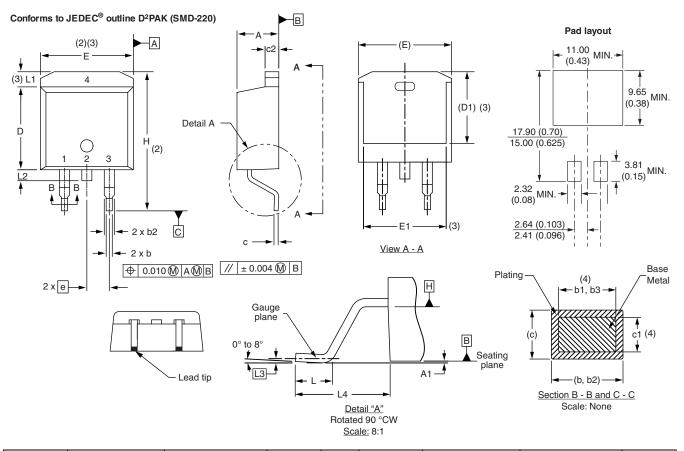


D²PAK

DIMENSIONS in millimeters and inches

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SHA



SYMBOL	MILLIM	IETERS	INC	HES	NOTES	SYMBOL	MILLIM	IETERS	INC	HES	NOTES	
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES		STWDUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			E	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100	BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5 M-1994

⁽²⁾ Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

⁽³⁾ Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

⁽⁵⁾ Datum A and B to be determined at datum plane H

⁽⁶⁾ Controlling dimension: inch

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-263AB

Revision: 08-Jul-15

1

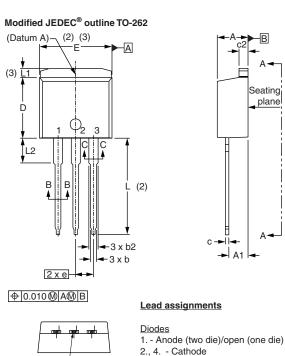
Outline Dimensions



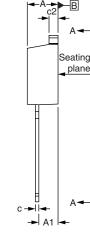
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TO-262

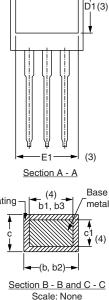
DIMENSIONS in millimeters and inches



Lead tip -



E1 Plating



Е

MILLIMETERS INCHES SYMBOL NOTES MIN. MAX. MIN. MAX. А 4.06 4.83 0.160 0.190 2.03 A1 3.02 0.080 0.119 b 0.51 0.99 0.020 0.039 b1 0.51 0.89 0.020 0.035 4 b2 1.14 1.78 0.045 0.070 1.14 1.73 0.045 0.068 4 b3 0.38 0.74 0.015 0.029 С 0.38 0.58 0.015 0.023 4 c1 1.14 1.65 0.045 0.065 c2 D 8.51 9.65 0.335 0.380 2 D1 6.86 8.00 0.270 0.315 3 Е 9.65 10.67 0.380 0.420 2, 3 E1 7.90 8.80 0.311 0.346 3 0.100 BSC 2.54 BSC е L 13.46 14.10 0.530 0.555 L1 _ 1.65 0.065 3 _ 3.36 0.132 0.146 L2 3.71

3. - Anode

Notes

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

(5) Controlling dimension: inches

⁽²⁾ Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

⁽³⁾ Thermal pad contour optional within dimension E, L1, D1 and E1

Outline conform to JEDEC TO-262 except A1 (maximum), (6) b (minimum), D1 (minimum) and L2 where dimensions derived the actual package outline

Revision: 11-Jul-2019

Document Number: 95419

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